

for actual use of this tabulation, please refer to:
A. Vasilescu and G. Lindstroem
Displacement damage in Silicon
on-line compilation: <http://sesam.desy.de/~gunnar/Si-dfuncs>

electron induced displacement damage in silicon
listed for kinetic energies between 300 keV and 200 MeV:
The only reliable data are from:
G.P.Summers et al., IEEE NS 40, No 6 (1993), 1372

| Ekin [MeV] | D/95MeVmb |
|------------|-----------|
| 3,000E-01 | 3,182E-03 |
| 5,000E-01 | 7,998E-03 |
| 7,000E-01 | 1,139E-02 |
| 1,000E+00 | 1,543E-02 |
| 2,000E+00 | 2,489E-02 |
| 3,000E+00 | 3,126E-02 |
| 5,000E+00 | 3,979E-02 |
| 7,000E+00 | 4,558E-02 |
| 1,000E+01 | 5,160E-02 |
| 2,000E+01 | 6,241E-02 |
| 3,000E+01 | 6,780E-02 |
| 5,000E+01 | 7,344E-02 |
| 7,000E+01 | 7,634E-02 |
| 1,000E+02 | 7,870E-02 |
| 2,000E+02 | 8,106E-02 |